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DC-4GHz, 2W, 28V LDMOS Fully matched PA Module

Description

The IMEH0040-2 is a 2-watt ,single stage integrated Power Amplifier Module, designed for broad band applications, with frequencies from DC to 4GHz. The module is 50 Ω input/output matched and requires minimal external components.



The module implements distributed power amplifier in form of multi chips, housed in cost effective plastic open cavity package, offers a much lower cost than traditional MMIC solutions.

Vds=28V, Idq=40mA, CW

Parameter	30MHz	0.5GHz	1.0GHz	1.5GHz	2.0GHz	2.5GHz	3.0GHz	3.5GHz	4.0GHz	Units
Linear Gain	13.7	13. 1	13.0	12.8	12.3	11.5	10.9	11.7	12.4	dB
Pout@Pin=24dBm	3. 5	3. 3	3. 2	2.9	2. 5	2.3	2.0	2. 5	2. 1	W
Gain@Pin=24dBm	11.5	11.1	11.1	10.6	10.0	9.6	9.1	9.9	9.3	dB
Eff@ Pin=24dBm	51	44	38	36	31	27	25	32	31	%

Product Features

• Operating Frequency Range: DC-4GHz

• Operating Drain Voltage: +28 V

• 50 Ω Input/Output

• Psat: ≥2W

• Small signal gain:>10.5dB, Power gain:>8dB

• Minimum efficiency:>20%

• 6x10 mm Surface Mount Package

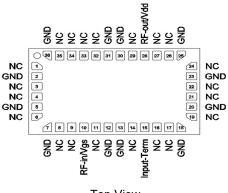
• Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC

• Much lower cost than GaN-based ultrawide band PA, due to LDMOS technology used

Applications

- Ultra Broadband Amplifiers
- Fiber Drivers
- Test Instrumentation
- EMC Amplifier Drivers
- 2-way Radios

Pin Configuration and Description



Top View



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Pin No.	Symbol	Description
28	RFout/Vdd	Transistor 1, Drain Bias & RF Output
10	RFin/Vgs	Transistor 1, RF Input &Gate Bias
15	Input-Term	Transistor 1, Input 50 ohm term
Others	NC	No connection
2,5,7,12, 13,18,20,23,25, 30, 31,36 Package Base	GND	DC/RF Ground. Must be soldered to EVB ground plane over array of vias for thermal and RF performance. Solder voids under Pkg Base will result in excessive junction temperatures causing permanent damage.

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
DrainSource Voltage	V _{DSS}	65	Vdc
GateSource Voltage	V_{GS}	-10 to +10	Vdc
Operating Voltage	V _{DD}	+32	Vdc
Storage Temperature Range	Tstg	-65 to +150	°C
Case Operating Temperature	Tc	+150	°C
Operating Junction Temperature	T₃	+200	°C

Table 2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Case	Do 10	10	°C/M
T _C = 87°C, T _J =175°C, DC test	R⊕JC	10	°C/W

Table 3. Electrical Characteristics

Parameter	Condition	Min	Тур	Max	Unit
Frequency Range		30		4000	MHz
Power Gain @ Psat		8			dB
P _{SAT}		33			dBm
Drain Efficiency @ P _{SAT}		20			%

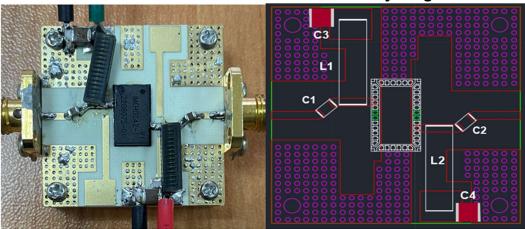
 $\textbf{Load Mismatch of per Section (On Test Fixture, 50 ohm system):} \quad V_{DD} = 28 \text{ V}, I_{DQ} = 40 \text{ mA}, f = 3.5 \text{ GHz}$

VSWR 10:1 at Psat pulse CW Output Power	No Device Degradation
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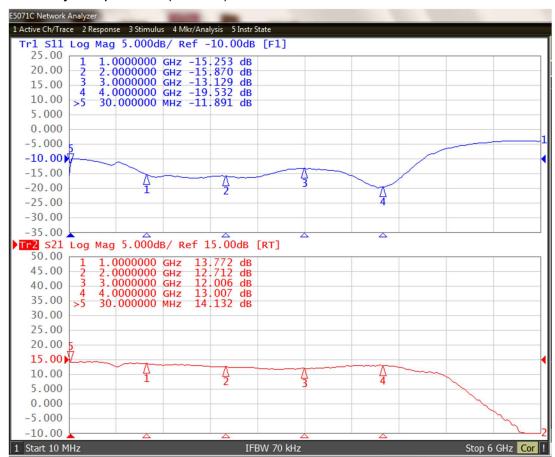
Reference Circuit of Test Fixture Assembly Diagram



		Part NO.	Vendor
C3,C4	10uF 100V chip Capacitor	C5750X7S2A106M230KB	TDK
C1,C2	50V 1uF Chip Capacitor	GRM21BR71H105KA12L	MuRata
L1,L2	1.3 uH 4.2A Inductor	4310LC-132KEC	Coilcraft
PCB	RO4350B,20mil,er=3.48		

TYPICAL CHARACTERISTICS

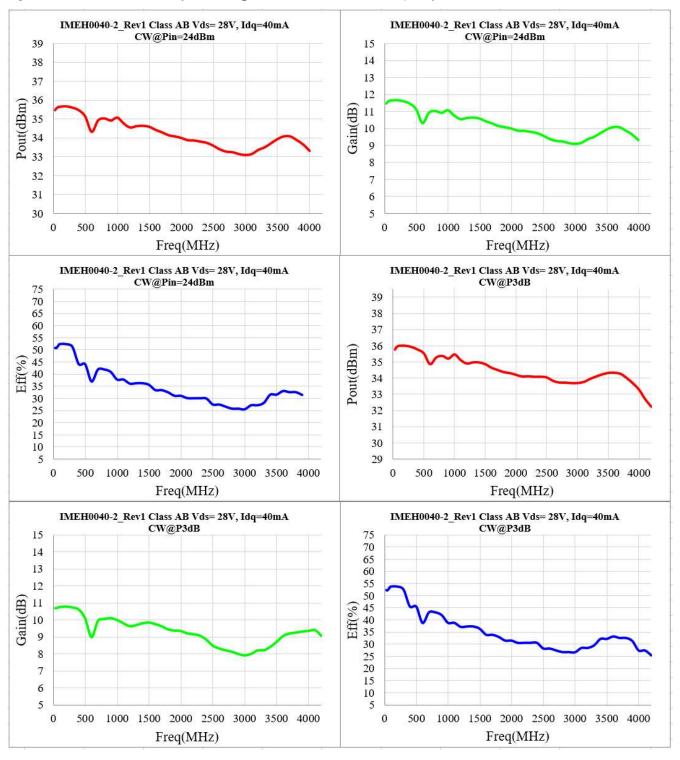
Figure 1. Network analyzer output S11/S21 (Pin=0dBm)





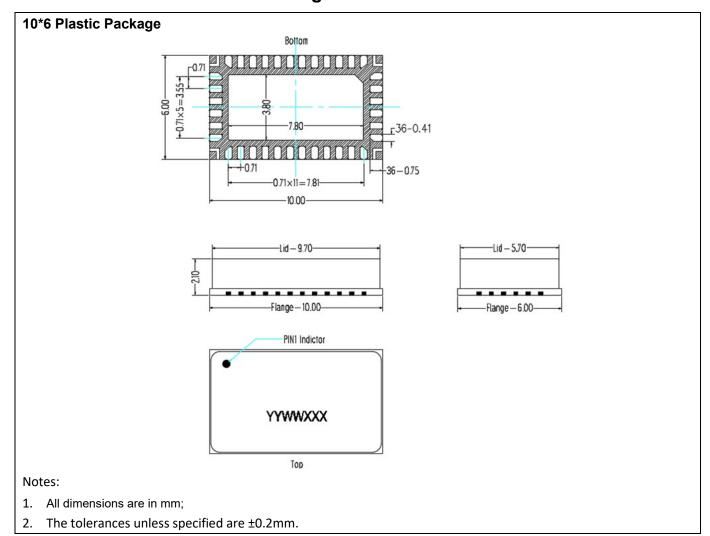
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Figure. Power Gain and, efficiency and Pout @Pin=24dBm ,and P3dB vs. Frequency



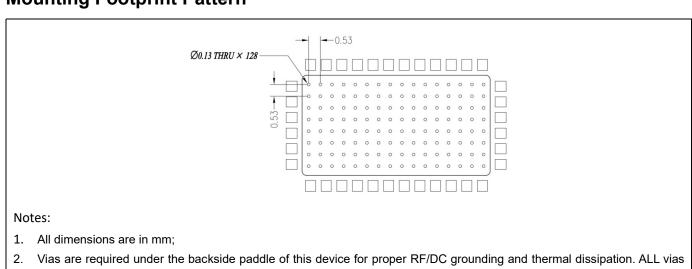
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Package Dimensions



Mounting Footprint Pattern

are PTH to ground.



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Revision history

Table 6. Document revision history

Date	Revision	Datasheet Status
2022/12/9	Rev 1.0	Production Datasheet

Application data based on ZHH-22-01

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